

Crystal Growth of Silicon for Solar Cells

Bearbeitet von
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1. Auflage 2009. Buch. xiv, 255 S. Hardcover

ISBN 978 3 642 02043 8

Format (B x L): 15,5 x 23,5 cm

Gewicht: 622 g

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Crystal Growth of Silicon for Solar Cells

(Eds.) K. Nakajima; N. Usami

2009, XIV, 255 p. 160 illus., 6 in color., Hardcover

ISBN: 978-3-642-02043-8